First Named Inventor	Craig T. Salling	INFORMATION DISCLOSURE STATEMENT
Serial No.	Filed herewith	
Filing Date	Filed herewith	
Group Art Unit	Unknown	
Examiner Name	Unknown	
Confirmation No.	Unknown	
Attorney Docket No.	400.054US03	
Title: WRITING TO FERROELECTRIC MEMORY DEVICES		

Commissioner for Patents
MS Patent Application
P.O. Box 1450
Alexandria, VA 22313-1450

In compliance with 37 C.F.R. §§ 1.56 and 1.97, *et seq.*, the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified Application. Applicant respectfully requests that this Information Disclosure Statement be entered and the references listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to MPEP §609, Applicant further requests that the Examiner initial next to each reference on the Form 1449 to indicate that the listed references have been considered. Applicant further requests that a copy of the initialed Form 1449 be returned with the next official communication.

Further pursuant to MPEP §609, because all of the references listed on the attached Form 1449 have been previously submitted and made of record in grandparent application, U.S. Patent 6,587,365 issued July 1, 2003, and parent application, U.S. Patent Application No. 10/205,989, filed July 26, 2002, copies of the references previously made of record in the parent applications are not submitted herewith.

If the Examiner has any questions or concerns regarding this application, please contact the undersigned at the number listed below.

Respectfully submitted,

Date: 10-06-2003

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F – 612/312-2250

First Named Inventor	Craig T. Salling
Serial No.	Filed Herewith
Filing Date	Filed Herewith
Group Art Unit	Unknown
Examiner Name	Unknown
Attorney Docket No.	400.054US03

INFORMATION DISCLOSURE STATEMENT FORM PTO-1449

Title: WRITING TO FERROELECTRIC MEMORY DEVICES

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	Country	No.			
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Other References	
Examiner Initials	Author, Title, Date, Pages, etc.

Examiner Signature		Date Considered	

*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.